SQM40061EL

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Automotive P-Channel 40 V (D-S) 175 °C MOSFET

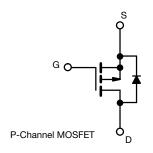


PRODUCT SUMMARY				
V _{DS} (V)	-40			
$R_{DS(on)} (\Omega)$ at $V_{GS} = -10 V$	0.0051			
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.0071			
I _D (A)	-100			
Configuration	Single			
Package	TO-263			

FEATURES

- TrenchFET[®] power MOSFET
- Package with low thermal resistance
- 100 % $R_{\rm q}$ and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \degree C$, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V _{DS}	-40	v	
Gate-source voltage		V _{GS}	± 20	V V	
Continuous drain current	T _C = 25 °C ^a	I _D	-100		
	T _C = 125 °C		-72		
Continuous source current (diode conduction) ^a		I _S	-100	А	
Pulsed drain current ^b		I _{DM}	-300		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-41		
Single pulse avalanche energy		E _{AS}	84	mJ	
Maximum power dissipation ^b	T _C = 25 °C	- P _D	150	w	
	T _C = 125 °C		50	~~~	
Operating junction and storage temperature ran	T _J , T _{stg}	-55 to +175	°C		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^c	R _{thJA}	40	°C/W	
Junction-to-case (drain)		R _{thJC}	1	0/10	

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0, I _D = -250 μA		-40	-	-	v	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$		-	-2.5	v	
Gate-source leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = -40 V	-	-	-1		
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	-50	μA	
		$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	-250		
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \le -5 V$	-50	-	-	Α	
		V _{GS} = -10 V	I _D = -30 A	-	0.0042	0.0051		
Ducin actures on state registeries a	Б	$V_{GS} = -10 V$	I _D = -30 A, T _J = 125 °C	-	-	0.0079		
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -10 V	I _D = -30 A, T _J = 175 °C	-	-	0.0094	Ω	
		V _{GS} = -4.5 V	I _D = -25 A	-	0.0059	0.0071		
Forward transconductance a		V _{DS} = -15 V, I _D = -30 A		-	103	-	S	
Dynamic ^b								
Input capacitance	C _{iss}			-	11 063	14 500		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{GS} = 0 V V _{DS} = -25 V, f = 1 MHz		847	1110	pF	
Reverse transfer capacitance	C _{rss}			-	757	1000	1	
Total gate charge ^c	Qg			-	185	280	nC	
Gate-source charge c	Q _{gs}	$V_{GS} = -10 V$	$V_{DS} = -20 \text{ V}, I_D = -50 \text{ A}$	-	25	-		
Gate-drain charge ^c	Q _{gd}			-	30	-		
Gate resistance	Rg	f = 1 MHz		1.8	3.6	5.4	Ω	
Turn-on delay time ^c	t _{d(on)}	V_{DD} = -20 V, R _L = 0.4 Ω I _D \cong -50 A, V _{GEN} = -10 V, R _g = 1 Ω		-	15	25		
Rise time ^c	t _r			-	180	280	ns	
Turn-off delay time ^c	t _{d(off)}			-	145	220		
Fall time ^c	t _f			-	160	250		
Source-Drain Diode Ratings and Char	acteristics ^b							
Pulsed current ^a	I _{SM}			-	-	-300	Α	
Forward voltage	V _{SD}	I _F =	-	-0.84	-1.5	V		

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%$

b. Guaranteed by design, not subject to production testing

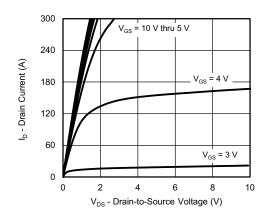
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

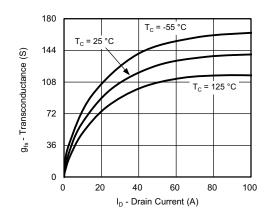
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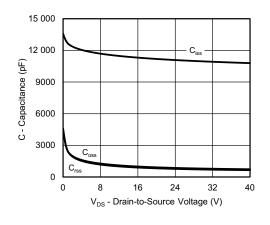
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



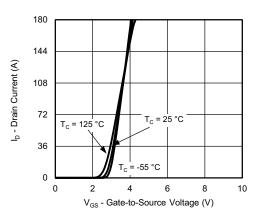
Output Characteristics



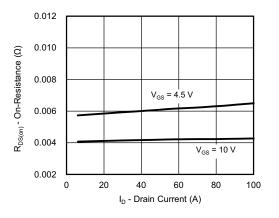
Transconductance



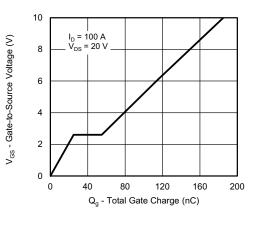
Capacitance



Transfer Characteristics



On-Resistance vs. Drain Current



Gate Charge

S17-1623-Rev. A, 23-Oct-17

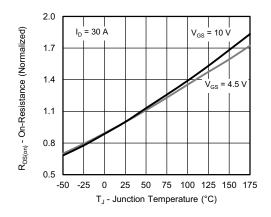
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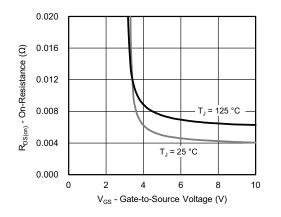
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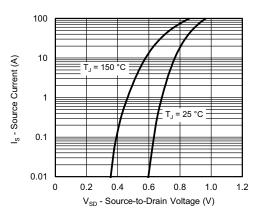
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



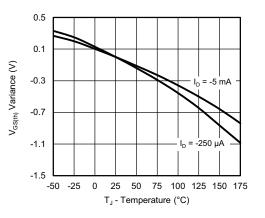
On-Resistance vs. Junction Temperature



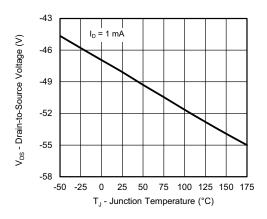
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage







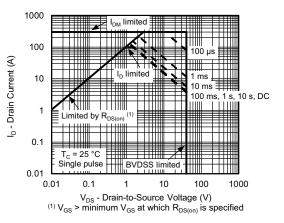


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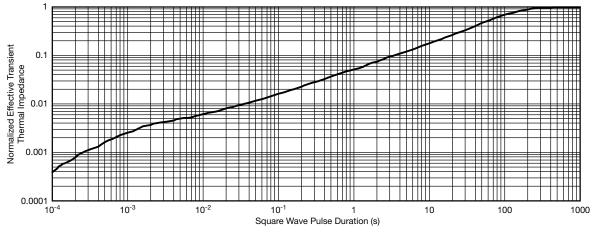
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Safe Operating Area

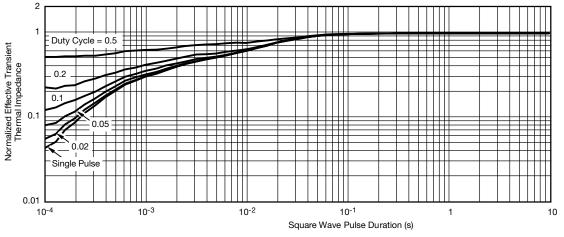


Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

S17-1623-Rev. A, 23-Oct-17

- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

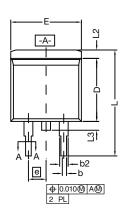
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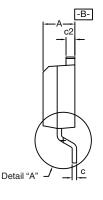
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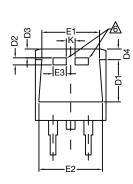


TO-263 (D²PAK): 3-LEAD

VERSION 1: FACILITY CODE = T

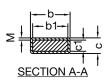








DETAIL A (ROTATED 90°)



		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
А		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
E3		0.072	0.078	1.829	1.981	
е		0.100 BSC		2.54 BSC		
К		0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
L4		0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	

Notes

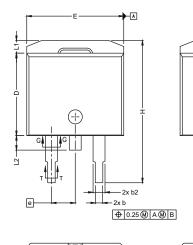
- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
- Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

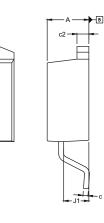
This feature is for thick lead.

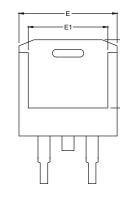
Revison: 28-Oct-2024

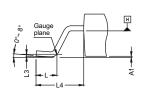


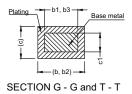
VERSION 2: FACILITY CODE = N











OPTION 1 2 leads



2

 \oplus

3 leads

DIM.	MIN.	MAX.		
A	4.36	4.56		
A1	0	0.25		
b	0.70	0.90		
b1	0.51	0.89		
b2	1.20	1.46		
b3	1.17	1.37		
с	0.38	0.694		
c1	0.38	0.534		
c2	1.19	1.34		
D	8.60	9.00		
D1	6.9	7.5		
E	10.15	10.55		
E1	8.1	8.7		
e	2.54 BSC			
Н	15.0	15.6		
L	1.9	2.5		
L1	-	1.65		
L2	-	1.78		
L3	0.25 typ.			
L4	4.78	5.28		
J1	2.56	2.96		
ECN: S24-1080-Rev. L, 28-Oct-2024 DWG: 5843				



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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